

F.E. (Semester - I) (Revised in 2007-08) Examination, May/June 2014 APPLIED SCIENCE - I

(Physics and Chemistry)

Duration: 3 Hours

Total Marks: 100

Instructions: 1) Answer one question from each Module.

- 2) Answer each Section in separate answer book.
- 3) Draw diagram wherever required.
- 4) Assume additional data if required.

SECTION-I (Physics)

Duration: 11/2 Hours

Marks: 50

Module - I

1. a) Prove that in reflected light radii of dark Newton's rings are proportional to square root of natural numbers.

5

b) Derive the expression for conductivity of a semiconductor in terms of mobility and carrier concentration. Hence write down the expression for resistivity of intrinsic semiconductor.

5

c) Two glass plates enclose a wedge shaped airfilm, touching at one edge and are separated by a wire at a distance 15 cm from the edge. A monochromatic light of wavelength 6000 A.U. is allowed to fall normally on the airfilm and fringe width is found to be 0.9 mm. Find the radius of the wire.

5

d) What is continuity equation. Derive continuity equation for electrons as well as holes in semiconductor:

10

- 2. a) Explain briefly the role of interference in :
 - i) AR coating
 - ii) Optical planeness of a surface.

5

b) Derive Einstein's relation between mobility μ and diffusion constant D. At 300 K if mobility of electron $\,\mu_n=2\,\mu_p$, then what will be the diffusion constant

 μ_n of electron. Given : For holes, $D_p = 4.68 \times 10^{-3} \text{ m}^2 \text{s}^{-1}$.

5 P.T.O.

SEM 1-2 (RC 07-08)



10

c) In a semiconductor the effective mass of the electron is 0.07m_o and that of a hole is 0.4 m_o, Where m_o is the free electron mass. Average relaxation time for the holes is half that for the electrons. Calculate mobility of the holes when the 5 mobility of electrons is 0.08 m²v⁻¹s⁻¹. d) Draw separate ray diagrams for reflected rays and transmitted rays in a parallel sided thin film. Derive the expression for optical path difference for both reflected and transmitted rays. Hence show the interference patterns of reflected and transmitted rays are complimentary to each other. 10 Module - II 3. a) Discuss acoustic diffraction method to find velocity of ultrasonic waves in 5 liquid. b) Explain magnetostriction method to produce ultrasonic waves. Draw necessary 5 circuit diagram. c) Distinguish between ionization chamber and GM counter. Explain why 5 quenching is carried out in GM counter. 5 d) Explain construction and working of magnetic lens. 5 e) Describe any two methods for detection of ultrasonic waves. a) Explain: i) Flaw detection in metals. 5 ii) Echo sounding in marine application. 5 b) Explain construction and working of electrostatic lens. c) Explain: i) What is electron gun? 5 ii) What is cavitation?

d) Explain the method of measuring frequency and wavelength of ac signal on

CRO. Draw neat labelled diagrams of CRT and CRO.



SECTION – II (Chemistry)

Duration: 11/2 Hours

Marks: 50

7

5

5

Module - III

- 5. a) Sketch the electrochemical cell and write the cell reactions and representation if Zn and Ag electrodes are dipped in their respective salt solutions ie Zn dipped in 0.001 M solution and Ag dipped in 0.01 M solution. Find out the cell potential (Given $E^{\circ}Zn = -0.76V$ and $E^{\circ}Ag = 0.8 V$) 8 b) The following cell Mg/Mg²⁺ (0.001M) || Mg²⁺(0.01M) | Mg was used to obtain electrical energy. State the principle behind working of this cell and explain its working with the help of neat diagram. Also find its EMF. (Given $E^{\circ}Mg = -2.37 \text{ V}$). 7 c) With the help of a neat labelled diagram explain the construction of the Ni-MH battery. 5 d) Explain the working of $H_2 - O_2$ fuel cell. 5 6. a) A Galvanic cell to be operated at 25°C is set up using the elements Ni and Ag. Write its cell representation and chemical reactions involved in the cell. Also find the EMF of the cell assuming that the Ni rod was dipped in its salts solution of 0.02 M and Ag rod was dipped in its salt solution of 0.05 M. (Given $E^{\circ}Ni = -0.23 \text{ V} \text{ and } E^{\circ} \text{ Ag} = 0.8 \text{ V})$ 8
 - b) The following cell Zn|Zn²⁺ (0.001M) ||Zn²⁺ (0.01M)|Zn was used in order to obtain electrical energy. State the principle behind working of this cell and explain its working with the help of a neat diagram. Find its Emf.
 - Write down the electrode reactions of lithium-manganese dioxide cell. Explain its working.
 - d) Give the construction and working of H₂ O₂ fuel cell.



Module - IV

7.	a)	Explain any four methods by which corrosion can be controlled or avoided.	10
	b)	Explain the process of PCB preparation using electroless method.	5
	c)	Explain the basic set up of an electroplating bath with the help of a suitable example.	5
	d)	What is stress corrosion? Explain.	5
8.	a)	A article made up of iron was exposed in the environment was found to have undergone corrosion. Explain any two mechanisms involved in the process of corrosion.	10
	b)	Give a brief account of electroless plating of Nickel.	5
	c)	What is anodization? How does it protect the metal from corrosion?	5
	d)	Explain electroplating of chromium.	5